

**HLMP-PB00-N0000 / HLMP-PM00-N0000**  
**HLMP-QB00-S0000 / HLMP-QM00-S0000**  
 High Power InGaN Subminiature Lamps



## Reliability Data Sheet

### Description

The following cumulative test results have been obtained from testing performed at Avago Technologies in accordance with the latest revision of MIL-STD-883.

Avago Technologies tests parts at the absolute maximum rated conditions recommended for the device. The actual performance you obtain from Avago Technologies parts depends on the electrical and environmental characteristics of your application but will probably be better than the performance outlined in Table 1.

### Failure Rate Prediction

The failure rate of semiconductor devices is determined by the junction temperature of the device. The relationship between ambient temperature and actual junction temperature is given by the following:

$$T_J (\text{°C}) = T_A (\text{°C}) + \theta_{JA} P_{AVG}$$

where

$T_A$  = ambient temperature in °C

$\theta_{JA}$  = thermal resistance of junction-to-ambient in °C/watt

$P_{AVG}$  = average power dissipated in watts

The estimated MTBF and failure rate at temperatures lower than the actual stress temperature can be determined by using an Arrhenius model for temperature acceleration. Results of such calculations are shown in the table on the following page using an activation energy of 0.43 eV (reference MIL-HDBK-217).

**Table 1. Life Tests**  
**Demonstrated Performance**

Colors	Stress Test Conditions	Total Device Hrs.	Units Tested	Units Failed	Point Typical Performance	
					MTBF	Failure Rate (%/1K Hours)
Dome (Blue)	$T_A = 55\text{°C}$ $I_F = 30 \text{ mA}$	56,000	56	0	56,000	≤1.79
Dome (Green)	$T_A = 55\text{°C}$ $I_F = 30 \text{ mA}$	56,000	56	0	56,000	≤1.79

**Table 2. Reliability Predictions ( $I_F = 30 \text{ mA}$ ) for InGaN devices  
Demonstrated Performance**

Ambient Temperature (°C)	Junction Temperature (°C)	Point Typical Performance in Time <sup>[1]</sup> (60% Confidence)		Performance in Time <sup>[2]</sup> (90% Confidence)	
		MTBF <sup>[1]</sup>	Failure Rate (%/1K Hours)	MTBF <sup>[2]</sup>	Failure Rate (%/1K Hours)
85	109	18,000	5.436	8000	12.517
75	99	26,000	3.826	11,000	8.810
65	89	38,000	2.642	16,000	6.082
55	79	56,000	1.786	24,000	4.112
45	69	85,000	1.180	37,000	2.716
35	59	132,000	0.760	57,000	1.750
25	49	210,000	0.477	91,000	1.098

Notes:

1. The point typical MTBF (which represents 60% confidence level) is the total device hours divided by the number of failures. In the case of zero failures, one failure is assumed for this calculation.
2. The 90% Confidence MTBF represents the minimum level of reliability performance which is expected from 90% of all samples. This confidence interval is based on the statistics of the distribution of failures. The assumed distribution of failures is exponential. This particular distribution is commonly used in describing useful life failures. Refer to MIL-STD-690B for details on this methodology.
3. A failure is any LED which does not emit light or maximum %  $I_V$  degradation is more than 50%.

### Example of Failure Rate Calculation

Assume a device operating 8 hours/day, 5 days/week. The utilization factor, given 168 hours/week is:

$$(8 \text{ hours/day}) \times (5 \text{ days/week}) / (168 \text{ hours/week}) = 0.25$$

The point failure rate per year (8760 hours) at 25°C ambient temperature is:

$$(0.086\% / 1\text{K hours}) \times (0.25) \times (8760 \text{ hours/year}) = 0.188\% \text{ per year}$$

Similarly, 90% confidence level failure rate per year at 25°C:

$$(0.197\% / 1\text{K hours}) \times (0.25) \times (8760 \text{ hours/year}) = 0.431\% \text{ per year}$$

**Table 3. Environmental Tests**

<b>Test Name</b>	<b>Reference</b>	<b>Test Conditions</b>	<b>Units Tested</b>	<b>Units Failed</b>	
Temperature Cycle	JESD22-A104	-55°C to 100°C, 15 min. dwell 5 min. transfer	5 cycles	625	0
			20 cycles	625	0
			50 cycles	625	0
			100 cycles	625	0
Humidity Life	JESD22-A101	85°C / 85%RH, 10mA, 1000hrs	56	0	
Humidity Storage Life	JESD22-A101	85°C / 85%RH, 1000hrs	56	0	
Low Temperature Life	JESD22-A108	-40°C, 30mA, 1000hrs	56	0	
Low Temperature Storage Life	JESD22-A103	-40°C, 1000hrs	56	0	
Room Temperature Life	JESD22-A108	25°C 30mA, 1000hrs	56	0	

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